

January 2000 Revised March 2000

74VCXH16373

Low Voltage 16-Bit Transparent Latch with Bushold

General Description

The VCXH16373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear to be transparent to the data when the Latch enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable ($\overline{\text{OE}}$) is LOW. When $\overline{\text{OE}}$ is HIGH, the outputs are in a high impedance state.

The VCXH16373 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

The 74VCXH16373 is designed for low voltage (1.65V to 3.6V) V_{CC} applications with output compatibility up to 3.6V.

The 74VCXH16373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.65V–3.6V V_{CC} supply operation
- 3.6V tolerant control inputs and outputs
- Bushold on data inputs eliminates the need for external pull-up/pull-down resistors
- \blacksquare t_{PD} (I_n to O_n)

3.0 ns max for 3.0V to 3.6V $\rm V_{CC}$ 3.4 ns max for 2.3V to 2.7V $\rm V_{CC}$

6.8 ns max for 1.65V to 1.95V V_{CC}

- Static Drive (I_{OH}/I_{OL})
 - ±24 mA @ 3.0V V_{CC}
 - ±18 mA @ 2.3V V_{CC}
 - ±6 mA @ 1.65V V_{CC}
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:

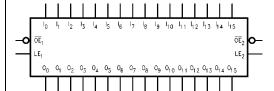
Human body model > 2000V Machine model > 200V

Ordering Code:

Ordering Number	Package Number	Package Description	
74VCXH16373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide	

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol



Pin Descriptions

Pin Names	Description
OE n	Output Enable Input (Active LOW)
LE _n	Latch Enable Input
I ₀ -I ₁₅	Bushold Inputs
O ₀ -O ₁₅	Outputs

Connection Diagram

	_		
			I
ŌE ₁ —	1	48	- LE ₁
o ₀ —	2	47	— I₀
01 —	3	46	— ا _ا
GND -	4	45	— GNE
02 —	5	44	— I ₂
03 -	6	43	- اع
v _{cc} –	7	42	— v _{cc}
04 -	8	41	— I₄
05 -	9	40	— I ₅
GND -	10	39	— GND
o ₆ —	11	38	ا ₋
07 -	12	37	— I ₇
08 —	13	36	— I ₈
o ₉ —	14	35	— I ₉
GND -	15	34	— GND
010 -	16	33	— I ₁₀
011 -	17	32	— I _{1 1}
v _{cc} -	18	31	— v _{cc}
012	19	30	— I _{1 2}
013 -	20	29	— I _{1 3}
GND -	21	28	— GNE
014 -	22	27	— I₁₄
015 -	23	26	— I ₁₅
$\overline{\text{OE}}_2$ —	24	25	- LE ₂
			I

Truth Tables

	Inputs		Outputs
LE ₁	OE ₁	1L	
L-1	O ∟ 1	I ₀ –I ₇	O ₀ -O ₇
Х	Н	Χ	Z
Н	L	L	L
Н	L	Н	Н
L	L	Χ	O ₀

	Inputs		Outputs
LE ₂	OE ₂	I ₈ -I ₁₅	O ₈ -O ₁₅
Х	Н	Х	Z
Н	L	L	L
Н	L	Н	Н
L	L	Х	O ₀

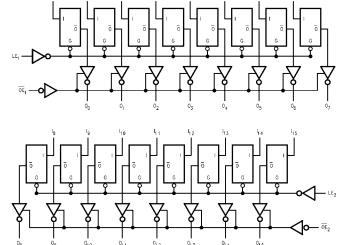
- H = HIGH Voltage Level
- L = LOW Voltage Level
- X = Immaterial (HIGH or LOW, control inputs may not float)
- Z = High Impedance
- O₀ = Previous O₀ before HIGH-to-LOW of Latch Enable

Functional Description

The 74VCXH16373 contains sixteen edge D-type latches with 3-STATE outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LEn) input is HIGH, data on the $\rm I_n$ enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time

its I input changes. When LE_n is LOW, the latches store information that was present on the I inputs a setup time preceding the HIGH-to-LOW transition on LE_n . The 3-STATE outputs are controlled by the Output Enable $(\overline{\mathsf{OE}}_n)$ input. When $\overline{\mathsf{OE}}_n$ is LOW the standard outputs are in the 2-state mode. When $\overline{\mathsf{OE}}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings(Note 1)

Supply Voltage (V_{CC}) -0.5V to +4.6V

DC Input Voltage (V_I)

 $\overline{\text{OE}}_{\text{n}}$, LE_n -0.5V to 4.6V I_0-I_{15} -0.5V to $V_{\text{CC}}+0.5\text{V}$

Output Voltage (V_O)

Outputs 3-STATED -0.5V to +4.6VOutputs Active (Note 2) -0.5V to V_{CC} +0.5V

DC Input Diode Current (I_{IK})

 $V_I < 0V$ —50 mA

DC Output Diode Current (I_{OK}) $V_O < 0V$ ---

 $V_{O} < 0V$ -50 mA $V_{O} > V_{CC}$ +50 mA

DC Output Source/Sink Current

 (I_{OH}/I_{OL})

DC V_{CC} or GND Current per

Supply Pin (I_{CC} or GND) ± 100 mA Storage Temperature Range (T_{STG}) -65° C to +150 $^{\circ}$ C

Recommended Operating Conditions (Note 3)

Power Supply

 $\begin{array}{c} \text{Operating} & 1.65 \text{V to } 3.6 \text{V} \\ \text{Data Retention Only} & 1.2 \text{V to } 3.6 \text{V} \\ \text{Input Voltage} & -0.3 \text{V to } \text{V}_{\text{CC}} \end{array}$

Output Voltage (V_O)

Output in Active States $0V \text{ to } V_{CC}$ Output in "OFF" State 0.0V to 3.6V

Output Current in I_{OH}/I_{OL}

 $\begin{array}{c} {\rm V_{CC} = 3.0V \; to \; 3.6V} & \pm 24 \; {\rm mA} \\ {\rm V_{CC} = 2.3V \; to \; 2.7V} & \pm 18 \; {\rm mA} \\ {\rm V_{CC} = 1.65V \; to \; 2.3V} & \pm 6 \; {\rm mA} \\ \end{array}$ Free Air Operating Temperature (T_A) $-40^{\circ}{\rm C} \; {\rm to \; +85^{\circ}C}$

Minimum Input Edge Rate (Δt/ΔV)

 $V_{IN} = 0.8V \text{ to } 2.0V, V_{CC} = 3.0V$ 10 ns/V

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: IO Absolute Maximum Rating must be observed.

Note 3: Floating or unused inputs must be held HIGH or LOW.

DC Electrical Characteristics (2.7V < $V_{\mbox{\footnotesize CC}} \leq$ 3.6V)

Symbol	Paramete	er	Conditions	V _{CC} (V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage			2.7-3.6	2.0		V
V _{IL}	LOW Level Input Voltage			2.7-3.6		0.8	V
V _{OH}	HIGH Level Output Voltage		$I_{OH} = -100 \mu A$	2.7-3.6	V _{CC} - 0.2		V
			$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
			$I_{OH} = -18 \text{ mA}$	3.0	2.4		V
			$I_{OH} = -24 \text{ mA}$	3.0	2.2		V
V _{OL}	LOW Level Output Voltage		$I_{OL} = 100 \mu A$	2.7–3.6		0.2	V
			$I_{OL} = 12 \text{ mA}$	2.7		0.4	V
			$I_{OL} = 18 \text{ mA}$	3.0		0.4	V
			$I_{OL} = 24 \text{ mA}$	3.0		0.55	V
I _I	Input Leakage Current	Control Pins	$0 \le V_1 \le 3.6V$	2.7–3.6		±5.0	μΑ
		Data Pins	$V_I = V_{CC}$ or GND	2.7–3.6		±5.0	μΑ
I _{I(HOLD)}	Bushold Input Minimum		V _{IN} = 0.8V	3.0	75		μА
	Drive Hold Current	Drive Hold Current		3.0	-75		μ.,
I _{I(OD)}	Bushold Input Over-Drive		(Note 4)	3.6	450		μА
	Current to Change State		(Note 5)	3.6	-450		μΛ
I _{OZ}	3-STATE Output Leakage		0 ≤ V _O ≤ 3.6V	2.7-3.6		±10	μА
				2.7-5.0		±10	μΛ
I _{OFF}	Power-OFF Leakage Curren	t	0 ≤ (V _O) ≤ 3.6V	0		10	μΑ
I _{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.7-3.6		20	μΑ
			$V_{CC} \le (V_O) \le 3.6V$ (Note 6)	2.7-3.6		±20	μΑ
ΔI_{CC}	Increase in I _{CC} per Input		$V_{IH} = V_{CC} - 0.6V$	2.7-3.6		750	μΑ

±50 mA

Note 4: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 5: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 6: Outputs disabled or 3-STATE only.

DC Electrical Characteristics (2.3V \leq $V_{CC} \leq$ 2.7V)

Symbol	Parameter		Conditions	V _{CC} (V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage			2.3 – 2.7	1.6		V
V _{IL}	LOW Level Input Voltage			2.3 – 2.7		0.7	V
V _{OH}	HIGH Level Output Voltage		$I_{OH} = -100 \mu A$	2.3 – 2.7	V _{CC} - 0.2		V
			$I_{OH} = -6 \text{ mA}$	2.3	2.0		V
			I _{OH} = -12 mA	2.3	1.8		V
			$I_{OH} = -18 \text{ mA}$	2.3	1.7		V
V _{OL}	LOW Level Output Voltage		I _{OL} = 100 μA	2.3 – 2.7		0.2	V
			I _{OL} = 12 mA	2.3		0.4	V
			I _{OL} = 18 mA	2.3		0.6	V
I _I	Input Leakage Current	Control Pins	0 ≤ V _I ≤ 3.6V	2.3 – 2.7		±5.0	μΑ
		Data Pins	V _I = V _{CC} or GND	2.3 – 2.7		±5.0	μА
I _{I(HOLD)}	Bushold Input Minimum		$V_{IN} = 0.7V$	2.3	45		
	Drive Hold Current		V _{IN} = 1.6V	2.3	-45		μΑ
I _{I(OD)}	Bushold Input Over-Drive		(Note 7)	2.7	300		
	Current to Change State		(Note 8)	2.7	-300		μΑ
loz	3-STATE Output Leakage		$0 \le V_O \le 3.6V$	2.3 – 2.7		±10	
			$V_I = V_{IH}$ or V_{IL}	2.3 – 2.1		±10	μΑ
l _{OFF}	Power-OFF Leakage Current	Power-OFF Leakage Current		0		10	μА
Icc	Quiescent Supply Current		$V_I = V_{CC}$ or GND	2.3 – 2.7		20	μА
			$V_{CC} \le (V_O) \le 3.6V \text{ (Note 9)}$	2.3 – 2.7		±20	μΑ

Note 7: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 8: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

Note 9: Outputs disabled or 3-STATE only.

DC Electrical Characteristics (1.65V \leq $V_{\mbox{\footnotesize CC}}$ < 2.3V)

Symbol	Parameter		Conditions	V _{CC} (V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage			1.65 - 2.3	$0.65 \times V_{CC}$		V
V _{IL}	LOW Level Input Voltage			1.65 - 2.3		$0.35 \times V_{CC}$	V
V _{OH}	HIGH Level Output Voltage		$I_{OH} = -100 \mu A$	1.65 - 2.3	V _{CC} - 0.2		V
			$I_{OH} = -6 \text{ mA}$	1.65	1.25		V
V _{OL}	LOW Level Output Voltage		$I_{OL} = 100 \mu\text{A}$	1.65 - 2.3		0.2	V
			$I_{OL} = 6 \text{ mA}$	1.65		0.3	V
I	Input Leakage Current	Control Pins	$0 \le V_1 \le 3.6V$	1.65 – 2.3		±5.0	μΑ
		Data Pins	$V_I = V_{CC}$ or GND	1.65 – 2.3		±5.0	μΑ
I _{I(HOLD)}	Bushold Input Minimum		V _{IN} = 0.57V	1.65	25		^
	Drive Hold Current		$V_{IN} = 1.07V$	1.65	-25		μА
I _{I(OD)}	Bushold Input Over-Drive		(Note 10)	1.95	200		^
	Current to Change State		(Note 11)	1.95	-200		μΑ
I _{OZ}	3-STATE Output Leakage		$0 \le V_O \le 3.6V$	4.05.00		±10	
			$V_I = V_{IH}$ or V_{IL}	1.65 - 2.3		±10	μΑ
I _{OFF}	Power-OFF Leakage Curren	Power-OFF Leakage Current		0		10	μΑ
I _{CC}	Quiescent Supply Current		$V_I = V_{CC}$ or GND	1.65 - 2.3		20	μΑ
			$V_{CC} \le (V_O) \le 3.6V \text{ (Note 12)}$	1.65 – 2.3		±20	μΑ

Note 10: An external driver must source at least the specified current to switch from LOW-to-HIGH.

 $\textbf{Note 11:} \ \textbf{An external driver must sink at least the specified current to switch from HIGH-to-LOW}.$

Note 12: Outputs disabled or 3-STATE only.

AC Electrical Characteristics (Note 13)

			T $_{A}$ = -40°C to +85°C, C $_{L}$ = 30 pF, R $_{L}$ = 500 Ω					
Symbol	Parameter	V _{CC} = 3	.3V ± 0.3V	V _{CC} = 2	.5V ± 0.2V	V _{CC} = 1.	8V ± 0.15V	Units
		Min	Max	Min	Max	Min	Max	
t _{PHL} , t _{PLH}	Prop Delay I _n to O _n	0.8	3.0	1.0	3.4	1.5	6.8	ns
t _{PHL} , t _{PLH}	Prop Delay LE to O _n	0.8	3.0	1.0	3.9	1.5	7.8	ns
t _{PZL} , t _{PZH}	Output Enable Time	0.8	3.5	1.0	4.6	1.5	9.2	ns
t _{PLZ} , t _{PHZ}	Output Disable Time	0.8	3.5	1.0	3.8	1.5	6.8	ns
t _S	Setup Time	1.5		1.5		2.5		ns
t _H	Hold Time	1.0		1.0		1.0		ns
t _W	Pulse Width	1.5		1.5		4.0		ns
toshl	Output to Output Skew		0.5		0.5		0.75	ns
t _{OSLH}	(Note 14)		0.5		0.5		0.73	113

Note 13: For $C_L = 50_P F$, add approximately 300 ps to the AC maximum specification.

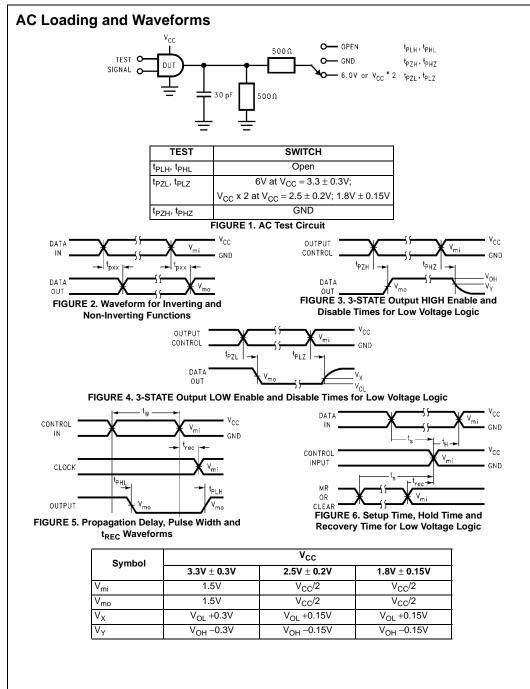
Note 14: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

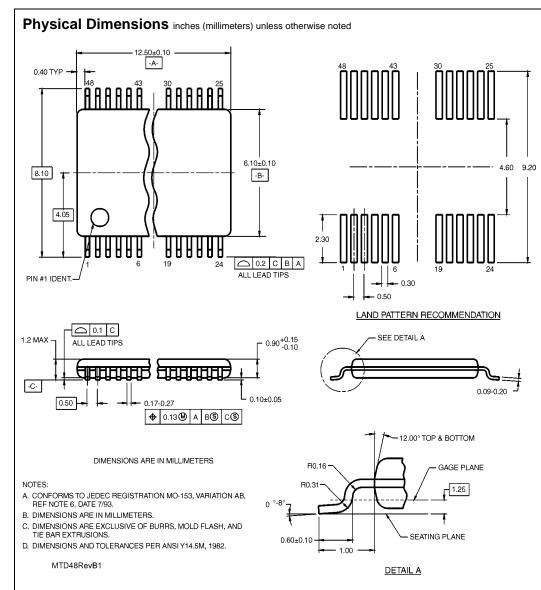
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = +25°C	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.25	
			2.5	-0.6	V
			3.3	-0.8	
V _{OHV}	Quiet Output Dynamic Valley V _{OH}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

Capacitance

Symbol	Parameter	Conditions	T _A = +25°C Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = 1.8V$, 2.5V or 3.3V, $V_{I} = 0V$ or V_{CC}	6	pF
C _{OUT}	Output Capacitance	$V_{I} = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	7	pF
C _{PD}		V _I = 0V or V _{CC} , f = 10 MHz, V _{CC} = 1.8V, 2.5V or 3.3V	20	pF





48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD48

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